

# Ten Thousand Series Photodetector Range

Shortform Catalogue

# General Description

IPL designs and manufactures a wide range of silicon photodetectors of both standard and custom design. Used in a wide range of pplications from low cost commercial to military and aerospace. they can detect and monitor electromagnetic radiation from ultraviolet through visible to near infra-red. Detectors for Beta and samma radiation can also be supplied.

he Ten Thousand Series is an established standard range of fully passivated silicon n-type, 'p' diffusion into 'n' substrate, photodiodes. They range from single high speed and high sensitivity PIN hotodiodes, through position sensors and arrays, to analogue and pulse detection hybrids. Supplied in industry standard packages, hey are available with various windows offering specific peak vavelength response and improved signal to noise ratios.

#### Product Types and Applications

PIN Photodiodes (IPL10020 - IPL10070)

Discrete, planar devices for applications including simple position sensing, ght intensity monitoring, light differential measurement, beam interrupt etection, and radiation emission monitoring.

#### Fibre Optic Interface (IPL10020BT)

lodified TO18 case with bead lens allows interface with industry standard MA connectors, giving high coupling efficiency and permitting an increase in fibre misalignment tolerance. Ideally suitable for short haul and LAN

#### Position Sensors (IPL10120, IPL10130)

With resolution capability better than 1 micron, applications include edge acking, light spot positioning, and laser beam alignment and tracking.

#### High Quality Calibrated (IPL10040DHC)

n NPL calibrated device for very precise light intensity measurement.

#### Arrays (IPL10220 series)

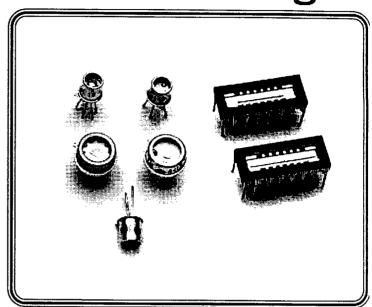
common cathode PIN photodiode arrays for applications including linear psition sensing, wide aperture detection, and edge and hole detection in rip materials.

#### Lybrid Sensors (IPL10530 series)

ositive going outputs for increasing light level, giving TTL or CMOS compatibility. Dual or single rail operation. All devices have analogue outputs, with the exception of the IPL10530C family which are high equency pulse detectors. Hybrid design offers excellent electrical noise nmunity. This makes these devices particularly valuable for monitoring low level signals in situations where the signal to noise ratio using a standard notodiode is unacceptable.

#### Custom Devices

addition to the Ten Thousand Series IPL supplies custom designed nsors. These are based on either standard detector chips or custom signed chips. A wide range of packaging techniques are available, including simple plastic mouldings, chip and wire hybrids, and surface ount assemblies. IPL can also design and supply detector signal processing ectronics.



#### **Packaging**

Industry standard packages are used and a range of window types are available. Standard options on windows include plain glass, optically flat glass, and near IR and eye response filtered glass. In addition the smaller devices are available in lensed packages which offer an improved gain and signal to noise ratio of around x10. Narrow band pass filters are also available.

#### Absolute Maximum Ratings

Operating temperature range: -40°C to +70°C Storage temperature range: -45°C to +100°C

Temperature coefficient of responsivity: +0.35% per °C Temperature coefficient of dark current: x2 per 8°C rise

Reverse breakdown voltage: 60V (not applicable to 10530 series)

#### Product Coding

Each device in the Ten Thousand Series has a unique code defining the detector chip, product type, package and window.

The first five digits after the 'IPL' identifier defines the product series and detector size.

In all devices, apart from the IPL10530 series, the sixth character defines the package type and the seventh character the window type.

For the IPL10220 series the subsequent digits define the number of diodes in the array.

For the IPL10530 series the sixth character defines the frequency response characteristics of the device, the seventh character the package type, and the eighth character the window type.

Whatever your optoelectronic sensor requirements, contact IPL.



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DS-001 Iss.1 Page 1



#### IPL10020 - IPL10070 - PIN Photodiodes

	Package		Peak Responsivity A/W # 1		Response		Dimensions	Dark Current	Capacitance	Response Time	
Device Code	Device Code Outline Tyl				Curve (Fig. 1)	Chip Outline Active Area mm x mm mm²		nA (VR=1V)	pF (VR=0V)	nS at λ=850nm (VR=10V RL=100R)	
IPL10020BW	1			1							
IPL10020BL	2	]	0.6	900							
IPL10020BT	3		0.6	900	1						
IPL10020BH	4	TO18									
IPL10020BE	1	1018	0.3	580	2						
IPL10020BF	2	]	0.5	360	2	1.0 x 1.0	0.66	0.1	9	4	
IPL10020BR	1		0.45	940	3	1			1		
IPL10020BS	2		0.45	240	د ا			}			
IPL10020DW			0.6	900	1	]		Į.	ļ		
IPL10020DE	5	TO39	0.3	580	2	]					
IPL10020DR			0.45	940	3	]					
IPL10030BW	1										
IPL10030BL	2	<b>[</b>	0.6	900	1				21		
IPL10030BH	4	TO18				1.5 x 1.5	1.75	0.25		7	
IPL10030BE	1		0.2	0.3 580	2						
IPL10030BF	2		0.5								
IPL10030BR	1		0.45 940	040	3		1.75	0.23	21	'	
IPL10030BS	2		0.43	240	J					1	
IPL10030DW	_	TO39	0.6	900	1						
IPL10030DE	5		`0.3	580	2			İ			
IPL10030DR			0.45	940	3					-	
IPL10040DW	5										
IPL10040DL	6		0.6	900	1					İ	
IPL10040DH	7										
IPL10040DE		TO39	0.3	580	2	2.5 x 2.5	5.5	0.7	56	10	
IPL10040DF	5		0.5	300							
IPL10040DR			0.45	940	3						
IPL10040DS	<u>]                                    </u>		0.43	740	,						
								cted to the case.			
All the above dev	ices can l	e suppli	ied with	isolated	d anode and	athode by addin	ng suffix 'I' to	the device code;	eg. IPL10020E	BWI	
IPL10050CW	8		0.6	000	1					1	
IPL10050CH	9	то	0.6	900	1	70-70	41.2	_	205	0.5	
IPL10050CE		TO8	0.3	540	2	7.0 x 7.0	41.3	4	325	25	
IPL10050CR	8		0.45	940	3						
IPL10060CW	8										
IPL10060CH	9	тов	0.6	900	1	0000	<b>-</b>			1	
IPL10060CE	- 8		0.3	540	2	9.0 x 9.0	78.5	9	735	100	
IPL10060CR	7 °	0.45		940	3						
IPL10070DW	5			940				0.25	21	<b>1</b>	
IPL10070DH	7	TOSO	0.6	940	1	07-47	1 77			23	
IPL10070DE	5	TO39	0.3	540	2	0.7 x 4.7	1.77				
IPL10070DR	7 <sup>3</sup>		0.45	940	3						

#### IPL10120 - Monolithic Two Element Annular Photodiode

ı	IPL10120AW	10		0.6	900	1					
	IPL10120AH	11	TOE	0.0	] 300	1	1.9mm dia.	1.37	0.2	100	25
	IPL10120AE	10	TO5	0.3	540	2	overall	per element	per element	l .	per element
i	IPL10120AR	10		0.45	940	3		ļ <b>-</b>	•	•	*

# IPL10130 - Monolithic Four Element Quadrant Photodiode

IPL10130AW	_12		0.6	900	1 1					
IPL10130AH	13	TOE	0.0	300	1	1.9mm dia.	0.66	0.1	45	15
IPL10130AE	12	TO5	0.3	540	2	overall	per quadrant	per quadrant	per quadrant	per quadrant
IPL10130AR	12		0.45	940	3				F 1	P q

# IPL10040 - High Quality NPL Calibrated PIN Photodiode

IPL10040DHC	7	TO39	0.6	900	1	2.5 x 2.5	5.5	0.7	56	10

# Shortform Catalogue

## IPL10220 Series - Monolithic PIN Photodiode Arrays

Device Code	Pacl Outline (fig.)	cage Type	Peak Responsivity per diode A/W at h		Response Curve (Fig. 1)	Number of diodes	Pitch of diodes mm	Active Area of each diode mm²	Dark Current per diode nA (VR=1V)	Capacitance per diode pF (VR=0V)	Response Time per diode nS (VR=10V RL=100R)
IPL10220AW4			0.6	900	1					9	
IPL10220AE4	16	TO5	0.3	580	2	4	1.0	0.66	0.1		
IPL10220AR4		103	0.45	940	3						
IPL10220AH4	17		0.6	900	1						
IPL10220NW8	18	16 pin				8					4
IPL10220NW14	19	DÎL 24 pin	0.6	900	1	14					
IPL10220NW16	20		0.6	300	1	16					
IPL10220NW22	21	DÎL				22					

#### PL10530 Series - Hybrid Analogue Output and Pulse Photodetectors

			111010800	Juspu				,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,			
Device Code	Paci Outline (fig.)	kage Type	Peak Responsivity A nm	Response Curve (Fig. 1)	Active Diode Area mm <sup>2</sup>	Supply Voltage Range V	Output Voltage at Peak Responsivity mV/µW/cm²	Dark Level Noise mV	Output Offset mV max.	Resp	iency oonse Hz   -6dB
IPL10530AAW IPL10530AAL	14		900	1			8.6 86	0.3	± 5		
IPL10530AAE IPL10530AAF	14 15		580	2		Dual Rail ± 2 to 18 or	4.3			200	300
IPL10530AAR IPL10530AAS	14 15		940	3			6.4 64				
IPL10530BAW IPL10530BAL	14 15		900	1			32		± 10	65	
IPL10530BAE IPL10530BAF	14 15	то5	580	2	1.75		160				100
IPL10530BAR IPL10530BAS	14 15		940	3		Single Rail 4 to 36	24 240				
IPL10530DAW IPL10530DAL	14 15		900	1			86 860				
IPL10530DAE IPL10530DAF	14 15		580	2			43 430	0.75			
IPL10530DAR IPL10530DAS	14 15	]	940	3			64 640				
IPL10530CAW IPL10530CAL	14 15		900	1		Dual Rail	64	0.65			
IPL10530CAE IPL10530CAF	14	то5	580	2	1.75	± 2 to 18	32		± 10	80	120
IPL10530CAR ■ IPL10530CAS	14		940	3		Single Rail 4 to 36	48 480	: ! i		Pulse detection	

# IPL10000 Series - Special Filter Products

Many of the above devices can be supplied with narrow band pass filters giving half power point width of around ±10nm.

Please contact IPL for further details.

# PL10000 Series - General Device Characteristics

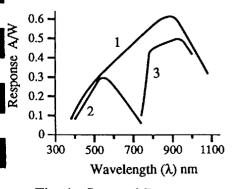


Fig. 1 Spectral Response

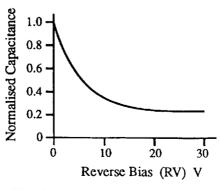


Fig. 2 Normalised Capacitance vs Reverse Bias

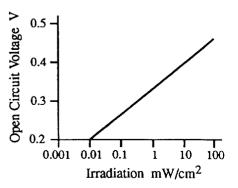
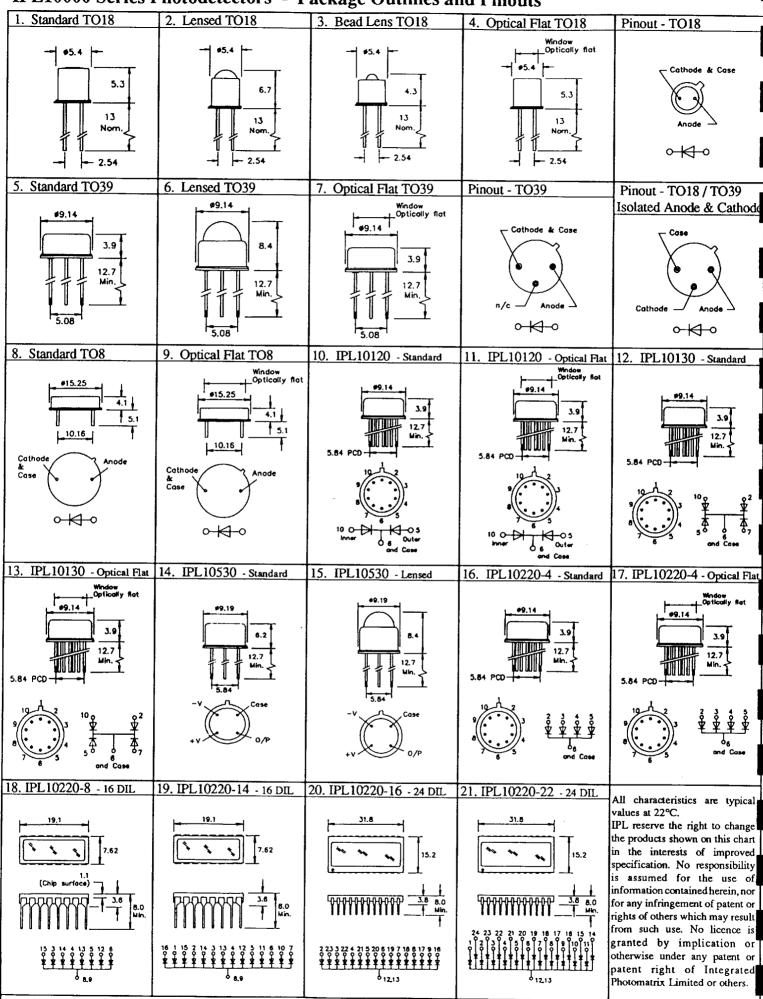


Fig. 3 Open Circuit Voltage vs Irradiation

# IPL10000 Series Photodetectors - Package Outlines and Pinouts





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